HZ20006000-50

50W-Solid State Broadband High Power Amplifier

Description

The HZ2000-6000-50 is a highly reliable amplifier which is guaranteed to deliver 50 watts of power within the 2000MHz to 6000MHz frequency range and related RF performance under specified temp and environmental conditions. When paired with the appropriate SDR source,it can do the jamming perfectly. This amplifier is suitable for use in defend systems in the V and U bands It utilizes the latest high power RF GaN transistors, with protection functions to ensure high availability.

Applicaton and Feature

- Utilizing third-generation GaN transistors
- Ultra-wide working bandwidth and instant bandwidth
- Excellent reliability
- Features temperature detection,standing-wave detection,and protection functions

Specifications of Products

Electrical Specifications					
Parameter	**Min**	**Typ**	**Max**	**Unit**	**Test Condition**
Operating frequency	2000		6000	MHz	
Instant bandwidth			200	MHz	Broadband signal,such as OFDM signal
Output power (Psat)	40	50		W	CW signal
Gain (small signal)	40		58	dB	Measured with VNA in swept frequency mode at -20dBm. Input power calibrated/measured at the amplifier input port.
Gain flatness (small signal)	-3		3	dB	Test condition the same as Gain
Gain adjustment range [note1]	20			dB	Test condition the same as Gain
Gain adjustment step size [note1]	0.5			dB	Test condition the same as Gain
Noise figure			20	dB	
Input VSWR			1.8		Measured with VNA in swept frequency mode at -20dBm. Input power calibrated/measured at the amplifier input port.

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Electrical Specifications					
Parameter	**Min**	**Typ**	**Max**	**Unit**	**Test Condition**
Spurious		-60		dBc	CW signal at the output power of 50W. Spurious defined as any non-harmonic amplifier outpur. Spurious measured in a 1kHz resolution bandwidth,10kHz video bandwidth.Specifications apply at offsets of greater than or equal to ±10kHz from the RF carrier. Maximum measurement frequency is 8GHz
Harmonics(2^{nd}, 3^{nd})	-10			dBc	CW signal source at output power of 50W
Operating voltage	24	28	32	V	Note:Output power capabilities and gain will vary with voltage
Operating current		10	12	A	CW signal source at output power of 50W
PA Enable/Disable time			1	μs	Measurement with of 50W CW output.Rise and fall time of amplifier output envelope recorded.Rise and fall times at 10%-90% of the output power in linear scale.PA Enable/ Disable signal set to 10kHz repetition rate and 50% duty cycle

Alarm and Protection	
Parameter	**Introductions**
Over temperature	When the temperature exceeds 80℃±5℃，the amplifier PIN7 will outputs +3.3V voltage and the amplifier will automatically shut down; When the temperature drops below 70℃±5℃, the amplifier will automatically turn on.
Over VSWR	When the output port of the amplifier is open or short,the amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down,the status will be locked . The alarm state will be cleared once pin 15 transmits a pulse signal
Over voltage [note1]	The amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down when the voltage exceeds 32V,the status will be locked. The alarm state will be cleared once pin 15 transmits a pulse signal
Over current [note1]	The amplifier PIN7 will outputs +3.3V voltage and the amplifier shut down when the current exceeds 14A.,the status will be locked. The alarm state will be cleared once pin 15 transmits a pulse signal

Environmental Specifications				
Parameter	**Min**	**Typ**	**Max**	**Unit**
Operating temperature	-40		+60	℃
Storage temperature	-55		+85	℃
Relative Humidity (non-condensing)			+95	%
Altitude	MIL-STD-810F Method 500.4			
Vibration/Shock	Pass MIL-STD-810F - Method 514.5/516.5 – Proc I			

Mechanical Specifications		
Parameter	**Value**	**Unit**
Dimension	200 x 158x 25	mm

Weight	1.4	kg
RF Connectors In/Out	Input: SMA-F Output: N-F	-
Control Connector	D-Sub 15-Pin Female	-
Power Supply Connector	Pull-core Capacitance	-
Cooling	External Heat sink	-

DC Interface Connector		
PIN#	**Description**	**Specification**
Grounding Post	GND	Ground Return
Pull-core Capacitance	VDD	Supply Voltage:+24V~32V,+28V Nominal
1	RS485 (-) [note1]	Serial Communication Bus
2	Temperature Reporting	Analog Output Voltage @ 10mV/°C with a 500mV offset (i.e. 0.75V = 25°C)
3	Address 1 (Reserved)	Hardware Address 1
4	Address 3 (Reserved)	Hardware Address 3
5	Attenuator setting [note1]	Voltage input in the range of 0.5-3.0VDC, 0.5VDC corresponds with minimum attenuation, 3.0VDC is maximum attenuation.
6	PA Enable	0/3.3V logic levels: Power Amplifier disable is a TTL Logic Low (0V). (Internally Pulled-High 3.3V)
7	Alarm	Amplifier Alarm indicator: Normally TTL Low A logic High indicates a fault condition, 0/3.3V Logic Levels
8	RS485(+) (Reserved) [note1]	Serial Communication Bus
9	Current Reporting	Analog output voltage range of 1V/10A (i.e. 1.5V = 15A)
10	Address 0(Reserved)	Hardware Address 0 – Least significant bit
11	Address 2	Hardware Address 2

DC Interface Connector		
PIN#	**Description**	**Specification**
	(Reserved)	
12	Address 4 (Reserved)	Hardware Address 4 – Most significant bit
13	Not Used	No Connection
14	Not Used	No Connection
15	Reset	Hardware reset Logic 0 to reset PA and clear latched faults

[note1]：This function is optional, and the optional model number is HZ20006000-50-M1.

Outline Drawing